

Kinetics of Gas Phase Addition Reactions of Trichlorosilyl Radicals. VI.¹⁾ Orientation of Additions to 2-Pentenes

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Synopsis. Addition reactions of $\cdot\text{SiCl}_3$ radicals to *cis*- and *trans*-2-pentene have been studied in the gas phase between 30 and 136 °C. The ratio of the rate of formation of 2- with 3-trichlorosilylpentane, R_2/R_3 , was found to vary with temperature or with HSiCl_3 concentrations ($1.47\text{--}17.6\ \mu\text{mol cm}^{-3}$). This variation was successfully interpreted by the decomposition of an adduct radical, $\text{CH}_3\text{CH}(\text{SiCl}_3)\dot{\text{C}}\text{HCH}_2\text{CH}_3$.

Quantitative studies of silyl radicals are of general interest now. Previously,²⁾ we reported that the addition of $\cdot\text{SiCl}_3$ radicals to *cis*-2-pentene gave 2- and 3-trichlorosilylpentane (2- and 3-TSP) and that the ratio of formation of the two isomers, R_2/R_3 , was 0.47 invariant either with temperature (133—182 °C) or with HSiCl_3 concentrations ($1.34\text{--}5.38\ \mu\text{mol cm}^{-3}$). It was then found, however, that R_2/R_3 was *ca.* 1.2 in a radiation induced reaction of HSiCl_3 with *cis*-2-pentene in cyclohexane at room temperature which was performed to prepare authentic samples of 2- and 3-TSP. It is of interest that the value of R_2/R_3 in the liquid phase is quite different from that in the gas phase. Further, orientation of addition in unsymmetrical olefins may be of importance in relation to the nature of the transition state.³⁾

In this connection, we studied the variation of R_2/R_3 with HSiCl_3 concentrations and with temperature between 30 and 136 °C to cover the temperature range below that of the previous study.

Experimental

Materials and procedures are essentially similar to those described earlier.²⁾ Mixtures of CH_3COCH_3 , 2-pentene, and HSiCl_3 were introduced into a cylindrical Pyrex cell of 137 cm³ which was heated in an electric oven. The light source was a 50 W medium pressure mercury arc. During this series of experiments, the rate of absorption of light was 7×10^{-12} einstein cm⁻³ min⁻¹. After photolysis, the reaction mixture was passed to a gas sampling loop and was immediately analyzed by GLC.

Results and Discussion

Mixtures of CH_3COCH_3 ($2.90\ \mu\text{mol cm}^{-3}$), HSiCl_3 ($8.70\ \mu\text{mol cm}^{-3}$) and *cis*- or *trans*-2-pentene ($0.58\ \mu\text{mol cm}^{-3}$) were photolyzed between 30 and 136 °C in the gas phase. Products were almost exclusively $(\text{CH}_3)_2\text{CHOSiCl}_3$ (A), 2-, and 3-TSP. The ratio of the rate of formation of the two isomers, R_2/R_3 , are shown in Fig. 1 as a function of temperature. R_2/R_3 was *ca.* 1.2 at 30 °C but decreased with an increase in temperature. At 136 °C it agreed with the value of 0.47 previously²⁾ obtained at higher temperatures. In addition, there was no significant difference in reactivity between *cis*- and *trans*-2-pentene.

The Arrhenius plots of the rate of formation of the respective products are given in Fig. 2.

The plot of $\log R_A$ against $1/T$ is seen to be linear; the

least-mean-squares treatment of the plot gives

$$\log(R_A/\mu\text{mol cm}^{-3} \text{ min}^{-1}) = 2.52 \pm 0.14 - (2.26 \pm 0.05) \times 10^3/T. \quad (1)$$

In the photolysis of CH_3COCH_3 in the presence of HSiCl_3 and 2-pentene, the addition of $\cdot\text{SiCl}_3$ radicals to CH_3COCH_3 ⁴⁾ and to 2-pentene²⁾ is known to constitute chain propagating steps as shown in the following.

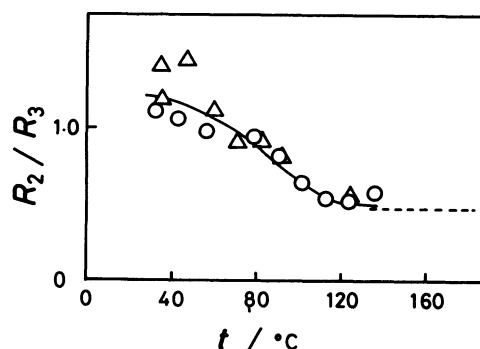
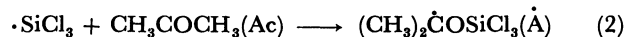


Fig. 1. Variation of R_2/R_3 with temperature. \circ : *cis*- Δ^2 - C_5H_{10} , \triangle : *trans*- Δ^2 - C_5H_{10} , -----: from Ref. 2. $[\Delta^2\text{-C}_5\text{H}_{10}] = 0.58$, $[\text{CH}_3\text{COCH}_3] = 2.90$, $[\text{HSiCl}_3] = 8.70\ \mu\text{mol cm}^{-3}$.

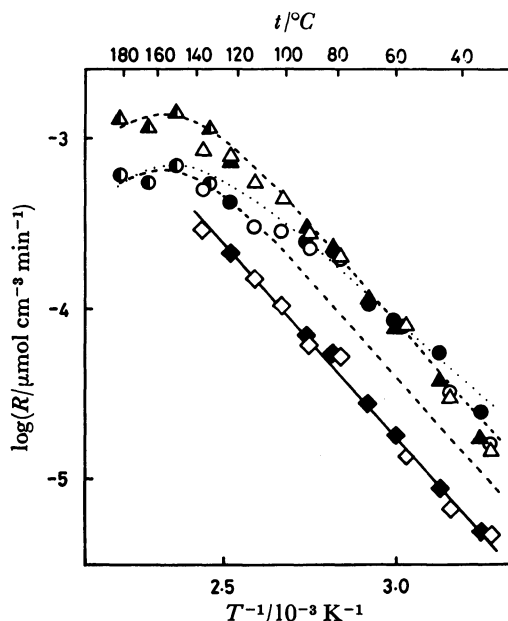


Fig. 2. Arrhenius plots of the rate of formation of the products. \diamond : A (Shifted by -0.5), \circ : 2-TSP, \triangle : 3-TSP, \bullet : 2-TSP from Ref. 2, \blacktriangle : 3-TSP from Ref. 2, -----: calculated (see text),: simulation curve based upon Eq. 11. Closed marks are from *trans*- Δ^2 - C_5H_{10} .

